

## SIZE EFFECTS AND DEFORMATION MECHANISMS IN DIAMOND AND SILICON

J.M. Wheeler, Laboratory for Nanometallurgy, ETH Zurich, Vladimir-Prelog-Weg 5, Zurich 8005, Switzerland  
Jeff.Wheeler@mat.ethz.ch

R. Raghavan, Structure and Nano-/Micromechanics of Materials, Max-Planck-Institute für Eisenforschung  
GmbH, Max-Planck-Strasse 1, 40237 Düsseldorf, Germany

J. Rabier, Institut P', CNRS-University of Poitiers-ENSMA, SP2MI, 86962 Futuroscope, France  
J. Wehrs, J. Michler,

Empa, Swiss Federal Laboratories for Materials Science and Technology, Laboratory for Mechanics of Materials  
and Nanostructures, Feuerwerkerstrasse 39, Thun CH-3602, Switzerland

Key words: microcompression, rate sensitivity, size effects, semiconductors

At ambient temperature and pressure, most of the semiconductor materials are brittle. Traditionally, use of confining pressure via indentation or a hydrostatic confining medium [1, 2] has been required to study the plasticity of such brittle materials. In the case of group IV semiconductors (Diamond, Silicon, and Germanium) the situation is further complicated by pressure-induced phase transformations occurring underneath the indentations. However, previous work has demonstrated that sample miniaturization can also prevent the onset of cracking and allow plastic deformation [3]. Recent advances in *in situ* instrumentation have enabled micro-compression techniques to extract temperature- and time-dependent deformation parameters [5, 6]. Thus, micro-pillar compression is a promising technique for investigating the plasticity of these semiconductors in their brittle regimes.

Previous work has noted a brittle-ductile transition in Silicon which is dependent on orientation, size, and temperature. This has been tied to transitions between partial and perfect dislocations in III-V semiconductors, but the extreme brittle character of silicon has prevented characterization of plastic flow in the low temperature regimes. In this work, [123]-oriented crystals are utilized to prevent the onset of cracking and allow plastic deformation. Micro-compression is shown to be capable of achieving incredibly high stresses ( $>100$  GPa), and this is applied to investigate the behavior of the hardest natural material - diamond - and its nearest analog – silicon.

### References

- [1] B. Kedjar, L. Thilly, J.L. Demenet, J. Rabier, *Acta Materialia*, 58 (2010) 1426-1440.
- [2] T. Suzuki, T. Yasutomi, T. Tokuoka, I. Yonenaga, *Physica status solidi (a)*, 171 (1999) 47-52.
- [3] J. Michler, K. Wasmer, S. Meier, F. Ostlund, K. Leifer, *Applied Physics Letters*, 90 (2007) 043123-043123.
- [4] L. Thilly, R. Ghisleni, C. Swistak, J. Michler, *Philos. Mag.*, (2012) 1-11.
- [5] S. Korte, W.J. Clegg, *Scripta Materialia*, 60 (2009) 807-810.
- [6] J.M. Wheeler, C. Niederberger, C. Tessarek, S. Christiansen, J. Michler, *International Journal of Plasticity*, 40 (2013) 140-151.